



## High sensitive photodiodes

### General Description

The epc3xx family products are high-sensitive photo diodes for light-barrier, light-curtain, and the like applications. These photo diodes are designed to be used in a reverse-bias mode.

This device allows the design of short to long range light barriers from a few millimeters up to tens of meters.

Using chips from the epc3xx product line, linear or two dimensional arrays can be formed for any application, be it triangulation, spot location, angle measurement, rotary encoders, or similar. Also, spectral sensitive detectors can easily be designed by applying color filters in front of the photo diodes.

Also, other mechanical dimensions are available upon request. It is possible to manufacture photo diodes of up to 15x15 mm or even bigger. Such a 15x15 mm device then would contain 450 individual photo diodes, each of them individually accessible. All diodes feature a very high quantum efficiency of 90% in the near IR range, a reverse breakdown voltage of up to 30 Volts and a response time down to less than 100ns. All devices are available upon request with optical bandpass filters.

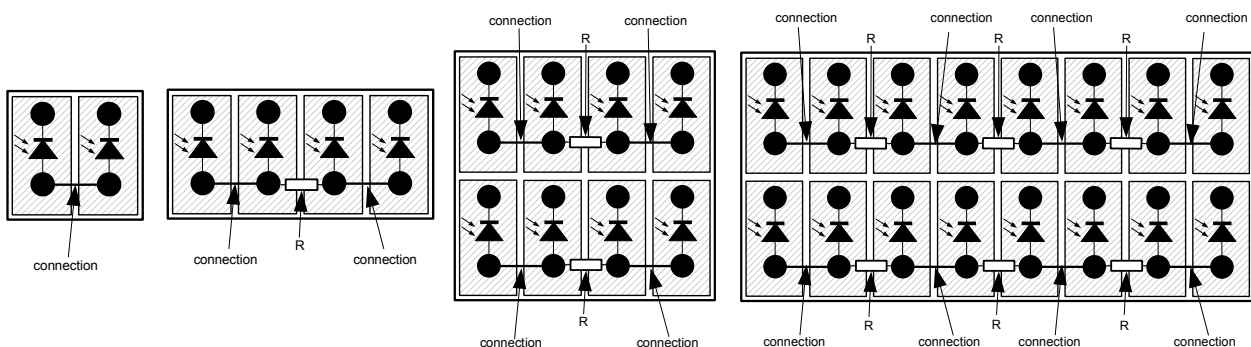
### Features

- Low dark current
- High quantum efficiency
- High dynamic range
- Diodes can be used in parallel
- CSP package with very small footprint
- Near infrared and visible version available
- Customer specific wavelength filter upon request

### Applications

- Light barriers ranging from millimeters to tens of meters
- Light curtains
- Smoke detectors
- Liquid detectors
- Heart beat monitors
- Position detection (rotary, linear, angle, etc.)
- IR remote control of Hi-Fi, TV sets and other equipment
- Leveling instruments
- Differential measurement
- Linear photo diode arrays

### Product Range Overview



R : refer to chapter "Electrical isolation between individual diodes"

Model	No. of Photo Diodes	Diode Length (mm)	Diode Width (mm)	Total Active Area (mm <sup>2</sup> )	Typ. Dark Current at 20°C (pA)	Ideal Bias Voltage (V)	Wavelength (nm)	Footprint
Single diode	1	1.0	0.5	0.43	40	5	400 - 1050	---
epc300	2	1.0	1.0	0.86	80	5	400 - 1050	CSP4
epc310	4	2.0	1.0	1.71	160	5	400 - 1050	CSP8
epc320	8	2.0	2.0	3.42	320	5	400 - 1050	CSP16
epc330	16	4.0	2.0	6.84	640	5	400 - 1050	CSP32

Type specific characteristics (all diodes of the array connected in parallel)

Absolute Maximum Ratings (Notes 1, 2)		Recommended Operating Conditions			
Reverse Voltage $V_R$	30.0 V	Min.	Max.	Units	
Breakdown Voltage between Diodes	10.0 V	Reverse Voltage ( $V_R$ )	1.5	20.0	V
Storage Temperature Range ( $T_S$ )	-40°C to +85°C	Operating Temperature ( $T_A$ )	-40	+85	°C
Lead Temperature solder, 4 sec. ( $T_L$ )	+260°C	Relative Humidity (non-condensing)	+5	+95	%

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended operating conditions indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see Electrical Characteristics.

**Note 2:** This device is a highly sensitive CMOS photodiodes with an ESD rating of JEDEC HBM class 2 (2kV to <4kV). Handling and assembly of this device should only be done at ESD protected workstations.

**Note 3:** Unless otherwise stated, measuring parameters are  $V_R = 5.0$  V,  $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ ,  $R_L = 50 \Omega$

**Note 4:** Unless otherwise stated, measurement data apply for individual photo diodes in multi diode chips

### General Characteristics (Notes 3, 4)

Symbol	Parameter	Conditions/Comments	Values			Units
			Min.	Typ.	Max.	
$\lambda_{S\max}$	Wavelength	max. Sensitivity		850		nm
$\lambda$	Wavelength Range	$S = 20\%$ of $S_{\max}$	400		1030	nm
$S_\lambda$	Spectral Sensitivity	$\lambda = 850\text{nm}$ , $V_R = 5\text{V}$ , $I_e = 1\text{ mW/cm}^2$ , type epc300		0.6		A/W
$\eta$	Quantum Efficiency	$\lambda = 850\text{nm}$ , $V_R = 5\text{V}$ , $I_e = 1\text{ mW/cm}^2$ , type epc300		90		%
$\phi$	Half angle			$\pm 60$		°
$V_O$	Open Circuit Voltage	$I_e = 0.5\text{ mW/cm}^2$		300		mV
$TC_V$	Temperature Coefficient of $I_{SC}$			0.15		%/K
$TC_O$	Temperature Coefficient of $V_O$			-3.0		mV/K

### Type Specific Characteristics @ +25°C (all diodes of the array connected in parallel)

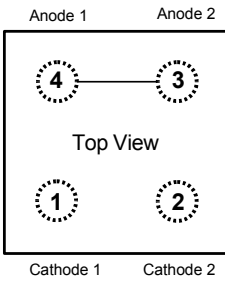
Symbol	Parameter	Conditions/Comments	Values			Units	
			Min.	Typ.	Max.		
$I_P$	Photo Current	per diode epc300 epc310 epc320 epc330	$V_R = 5\text{V}$ , $I_e = 1\text{ mW/cm}^2$ , $\lambda = 850\text{ nm}$ (NIR filter centered on 850nm)		2.5		$\mu\text{A}$
					5		
					10		
					20		
					40		
$I_R$	Dark Current *	per diode epc300 epc310 epc320 epc330	$V_R = 5\text{ V}$ , $T_A = 20^\circ\text{C}$		40pA	2.5nA	
					80pA	5.0nA	
					160pA	10nA	
					320pA	20nA	
					640pA	40nA	
$I_{SC}$	Short-circuit Current	per diode epc300 epc310 epc320 epc330	$I_e = 1\text{ mW/cm}^2$		2.5		$\mu\text{A}$
					5		
					10		
					20		
					40		

\* selected types available upon request

Symbol	Parameter		Conditions/Comments	Values			Units
				Min.	Typ.	Max.	
$t_r$	Rise/Fall Time	all types	photo current measured at $R_L = 50 \Omega$ , $\lambda = 850 \text{ nm}$ , $I_P = 200 \mu\text{A}$ $V_R = +1.5 \text{ V}$ $V_R = +5.0 \text{ V}$ $V_R = +10.0 \text{ V}$				ns
					300		
					150		
					90		
$C_O$	Capacitance	per diode	$V_R = +5\text{V}$ , $f = 100\text{kHz}$ , $E = 0$		5		pF
		epc300			10		
		epc310			20		
		epc320			40		
		epc330			80		
NEP	Noise Equivalent Power	per diode	$V_R = 5 \text{ V}$		$4.2 \times 10^{-15}$		W/ $\sqrt{\text{Hz}}$
		epc300			$6.0 \times 10^{-15}$		
		epc310			$8.4 \times 10^{-15}$		
		epc320			$1.2 \times 10^{-14}$		
		epc330			$1.7 \times 10^{-14}$		
$C_T$	Cross Talk Suppression	epc320 epc330	between individual photo diodes on the same chip, if the voltage difference $V_{diff}$ is $<100\text{mV}$ between individual diodes (cathodes)		50		dB

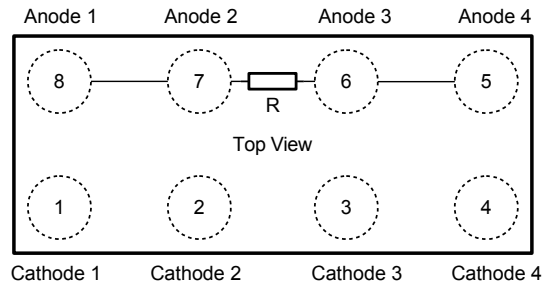
Connection Diagrams

epc300

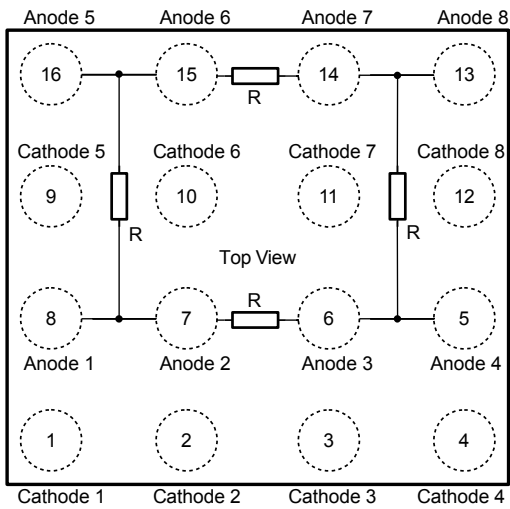


The structure of the diodes shown in the figure to the left is the same for all individual diodes on the chip also for the models epc310, epc320, and epc330. Always two photo diodes are paired and have shorted anodes as shown in the figure.  
R : refer to chapter "Electrical isolation between individual diodes"

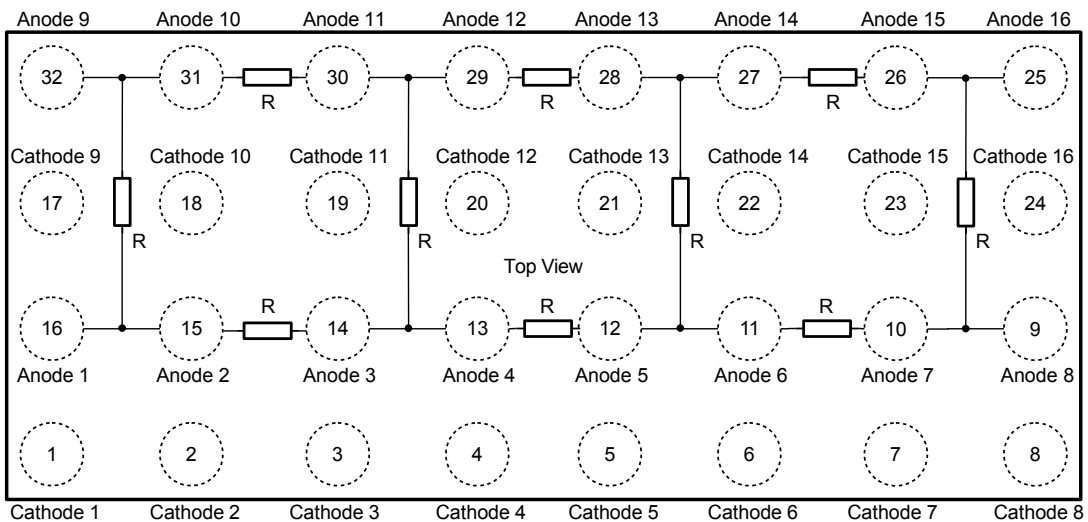
epc310



epc320

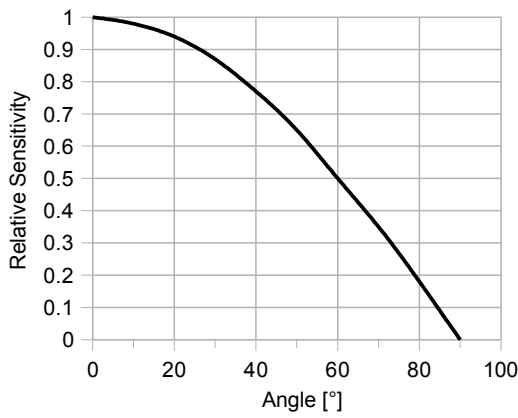


epc330

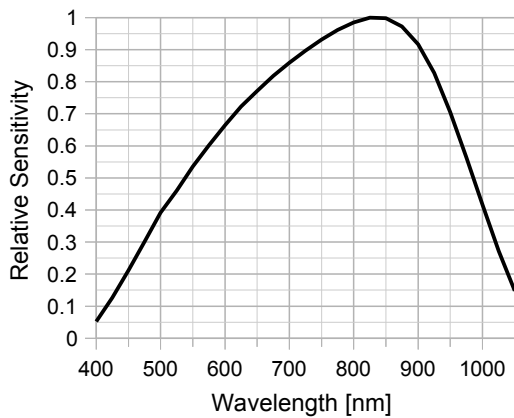


### Other Parameters

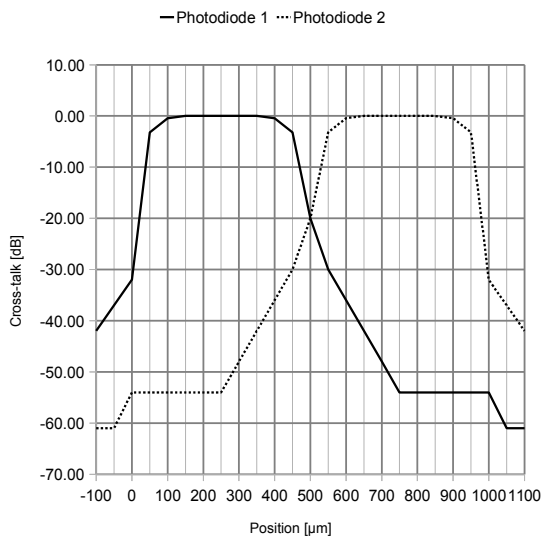
(typical values,  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{DD} = 5.0\text{V}$ ,  $I_{PD}=0\text{mA}$ )



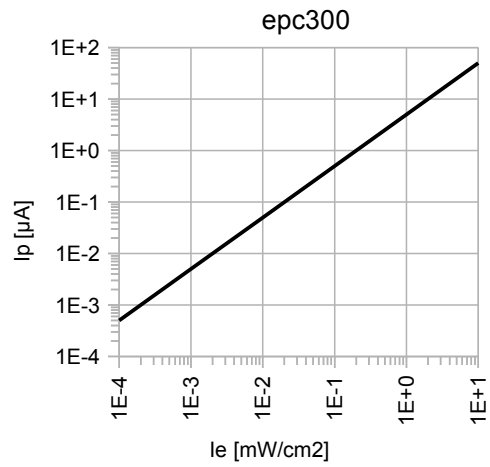
Relative sensitivity vs. illumination angle



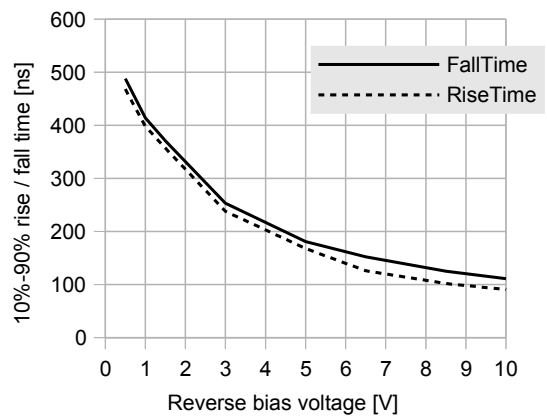
Relative spectral sensitivity



Cross-talk between a pair of photodiodes



Photocurrent  $I_p = f(I_e)$ ,  $V_R = 5\text{V}$ ,  $\lambda = 850\text{nm}$



Rise/ fall time versus reverse bias voltage

## Application Information

### Light Barrier Application

The following circuit uses an epc3xx photo diode with an epc13x PD amplifier chip. This circuit offers a very high AC photo current sensitivity and a tremendous DC backlight suppression.

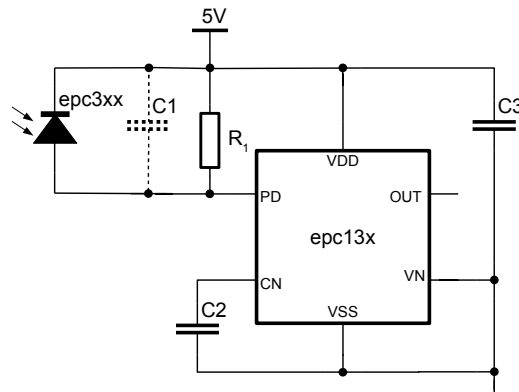


Figure 1: Typical schematic circuit using an epc13x PD amplifier

### Recommended Components Values

R1: 27k (bias resistor). Sensitivity can be reduced by the reduction of this resistor.

C1: Usually not needed. May be up to 100 pF (refer to the epc13x data sheet).

C2: 33nF (DC input current filter capacitor)

C3: 100nF or more (power supply filter capacitor)

### Spectral Sensitivity

This photo diode contains an anti-reflection coating on the photosensitive surface. Standard versions have no optical filter in order to allow applications from the near UV to the near IR range. However, optical filters deposited on the photosensitive surface are available upon request. The filter parameters can be adjusted in a wide range according to specific customer requirements.

### Electrical Isolation between individual Diodes

The individual diodes are located on a monolithic silicon chip. Thus, the electrical isolation between the individual diodes is not as good as with diodes on separate substrates. The substrate is conductive in x and y direction between all anodes, e.g. indicated in schematics by "R". In x direction between the anode pairs ca. 20kΩ is a typical value. They must not be used as resistor components.


### Design rules

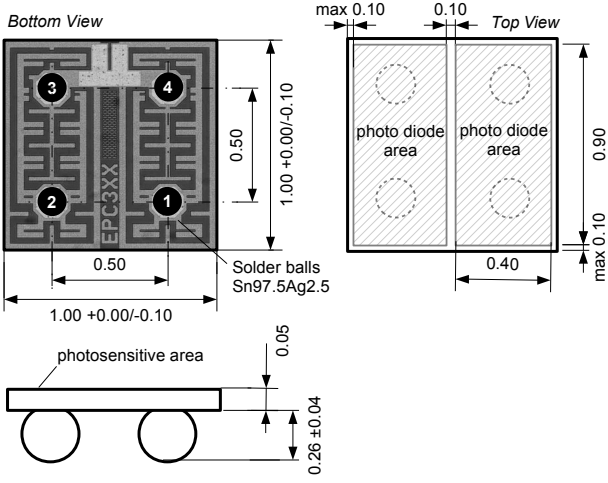
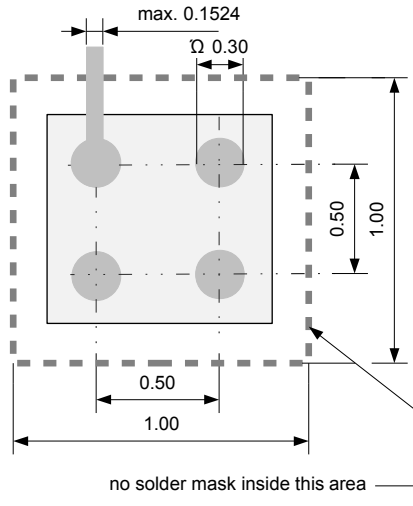
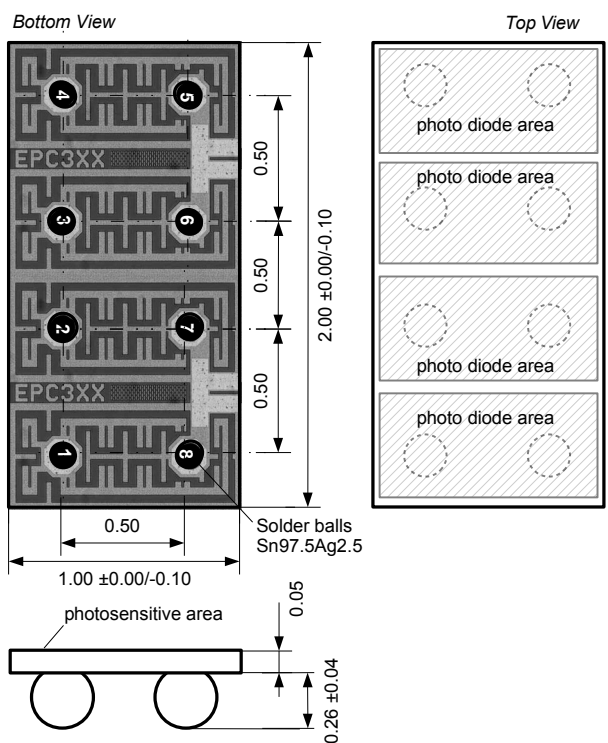
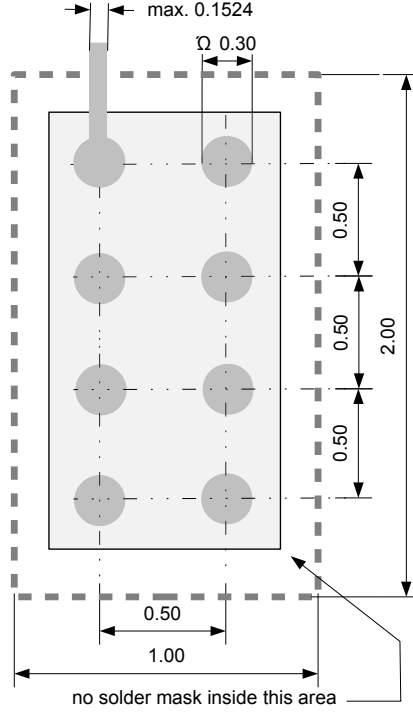
On chip are the anodes metallic connect together by pairs. The user has to take care, that all anode pins are connected to the same voltage level (refer to above section).

All pins of the diode array should be connected electrical-wise.

The biasing of the cathodes can be individual. Their voltage levels should be equal best match.

### Layout Information

(all measures in mm, )

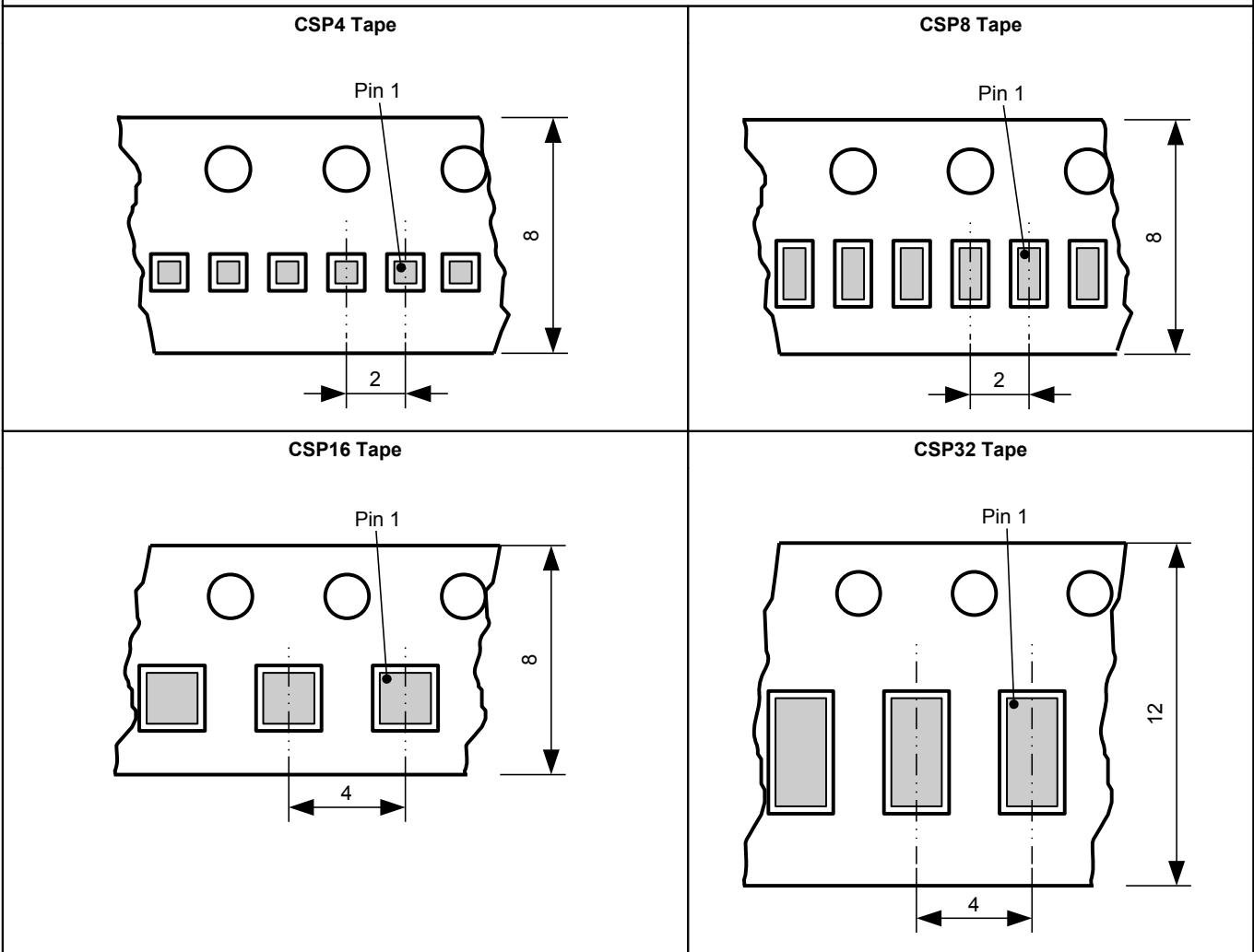
Package	Mechanical Dimensions	Layout Recommendations
CSP4	 <p><b>Bottom View</b></p> <p><b>Top View</b></p> <p>Solder balls Sn97.5Ag2.5</p> <p>photosensitive area</p>	 <p>no solder mask inside this area</p>
CSP8	 <p><b>Bottom View</b></p> <p><b>Top View</b></p> <p>Solder balls Sn97.5Ag2.5</p> <p>photosensitive area</p>	 <p>no solder mask inside this area</p>





### Packaging Information

(all measures in mm)



### Tape & Reel Information

The devices are mounted on embossed tape for automatic placement systems. The tape is wound on 178 mm (7 inch) or 330 mm (13 inch) reels and individually packaged for shipment. General tape-and-reel specification data are available in a separate data sheet and indicate the tape sizes for various package types. Further tape-and-reel specifications can be found in the Electronic Industries Association (EIA) standard 481-1, 481-2, 481-3.

epc does not guarantee non-empty cavities. Thus, pick-and-place machines should check the presence of a chip during picking.

It is highly recommended to use underfill after assembly of the chips to the PCB.

### Ordering Information

Part Name	Package	RoHS compliance	Packaging Method
epc300-CSP4	CSP4	Yes	Reel
epc310-CSP8	CSP8	Yes	Reel
epc320-CSP16	CSP16	Yes	Reel
epc330-CSP32	CSP32	Yes	Reel

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